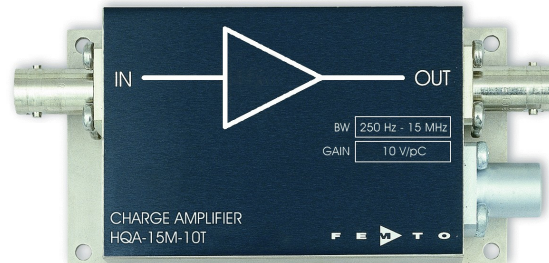




Preliminary Datasheet

HQA-15M-10T

High Frequency Charge Amplifier



Features	<ul style="list-style-type: none"> • High Gain of 10 V/pC • Wide Operating Range from 250 Hz to 15 MHz • Low Input Noise of 40×10^{-21} C/$\sqrt{\text{Hz}}$ and 700 pV/$\sqrt{\text{Hz}}$ • Optimized for Sinusoidal Signals from AC Coupled Charge Sources 																																																																																									
Applications	<ul style="list-style-type: none"> • Pyro- and Piezoelectric Detectors • Tuning Fork Quartz Crystals • Length Extension Resonators • Atomic Force Microscopy • Optical Measurements • Charged Particle Beam Monitoring 																																																																																									
Specifications	<p><i>Test Conditions</i> $V_s = \pm 15 \text{ V}, T_a = 25^\circ\text{C}$</p> <table border="0"> <tr> <td style="vertical-align: top;">Gain</td> <td>Charge Gain</td> <td>10^{13} V/C</td> <td></td> </tr> <tr> <td></td> <td>Equivalent Current Gain</td> <td>1.6×10^6 V/A</td> <td>(@ 1 MHz sinusoidal input signal)</td> </tr> <tr> <td></td> <td>Gain Accuracy</td> <td>$\pm 3 \%$</td> <td></td> </tr> <tr> <td style="vertical-align: top;">Bandwidth</td> <td>Lower Cut-Off Frequency (-3 dB)</td> <td>250 Hz</td> <td></td> </tr> <tr> <td></td> <td>Upper Cut-Off Frequency (-3 dB)</td> <td>15 MHz</td> <td>(with max. 100 pF source capacitance)</td> </tr> <tr> <td style="vertical-align: top;">Input</td> <td>Input Impedance</td> <td>1 GΩ // 10 nF</td> <td></td> </tr> <tr> <td></td> <td>Effective AC Input Impedance</td> <td>20 Ω @ 1MHz</td> <td></td> </tr> <tr> <td></td> <td>Input Charge Noise</td> <td>40×10^{-21} C/$\sqrt{\text{Hz}}$</td> <td>(with open input)</td> </tr> <tr> <td></td> <td></td> <td>90×10^{-21} C/$\sqrt{\text{Hz}}$</td> <td>(with 100 pF source capacitance)</td> </tr> <tr> <td></td> <td>Equivalent Input Current Noise</td> <td>250 fA/$\sqrt{\text{Hz}}$</td> <td>(with open input)</td> </tr> <tr> <td></td> <td>(@ 1 MHz sinusoidal input signal)</td> <td>570 fA/$\sqrt{\text{Hz}}$</td> <td>(with 100 pF source capacitance)</td> </tr> <tr> <td></td> <td>Input Voltage Noise</td> <td>700 pV/$\sqrt{\text{Hz}}$</td> <td>(@ 1 MHz)</td> </tr> <tr> <td></td> <td>Max. Input Charge</td> <td>1 pC peak-peak</td> <td></td> </tr> <tr> <td style="vertical-align: top;">Output</td> <td>Output Voltage Range</td> <td>10 V peak-peak</td> <td>(@ $\geq 1 \text{ M}\Omega$ load, for linear operation)</td> </tr> <tr> <td></td> <td>Output Impedance</td> <td>50 Ω</td> <td>(terminate with $\geq 1 \text{ M}\Omega$ load for best performance)</td> </tr> <tr> <td></td> <td>Integrated Broadband Noise</td> <td>typ. 20 mV peak-peak or 3.5 mV rms</td> <td>(@ $\geq 1 \text{ M}\Omega$ load)</td> </tr> <tr> <td style="vertical-align: top;">Power Supply</td> <td>Supply Voltage</td> <td>$\pm 15 \text{ V}$</td> <td></td> </tr> <tr> <td></td> <td>Supply Current</td> <td>$\pm 35 \text{ mA}$ typ. (depends on operating conditions, recommended power supply capability min. $\pm 100 \text{ mA}$)</td> <td></td> </tr> <tr> <td style="vertical-align: top;">Case</td> <td>Weight</td> <td>200 g (0.44 lb.)</td> <td></td> </tr> <tr> <td></td> <td>Material</td> <td>AlMg4.5Mn, nickel-plated</td> <td></td> </tr> <tr> <td style="vertical-align: top;">Temperature Range</td> <td>Storage Temperature</td> <td>-40 $^\circ\text{C}$ to +100 $^\circ\text{C}$</td> <td></td> </tr> <tr> <td></td> <td>Operating Temperature</td> <td>+20 $^\circ\text{C}$ to +40 $^\circ\text{C}$</td> <td></td> </tr> </table>		Gain	Charge Gain	10^{13} V/C			Equivalent Current Gain	1.6×10^6 V/A	(@ 1 MHz sinusoidal input signal)		Gain Accuracy	$\pm 3 \%$		Bandwidth	Lower Cut-Off Frequency (-3 dB)	250 Hz			Upper Cut-Off Frequency (-3 dB)	15 MHz	(with max. 100 pF source capacitance)	Input	Input Impedance	1 G Ω // 10 nF			Effective AC Input Impedance	20 Ω @ 1MHz			Input Charge Noise	40×10^{-21} C/ $\sqrt{\text{Hz}}$	(with open input)			90×10^{-21} C/ $\sqrt{\text{Hz}}$	(with 100 pF source capacitance)		Equivalent Input Current Noise	250 fA/ $\sqrt{\text{Hz}}$	(with open input)		(@ 1 MHz sinusoidal input signal)	570 fA/ $\sqrt{\text{Hz}}$	(with 100 pF source capacitance)		Input Voltage Noise	700 pV/ $\sqrt{\text{Hz}}$	(@ 1 MHz)		Max. Input Charge	1 pC peak-peak		Output	Output Voltage Range	10 V peak-peak	(@ $\geq 1 \text{ M}\Omega$ load, for linear operation)		Output Impedance	50 Ω	(terminate with $\geq 1 \text{ M}\Omega$ load for best performance)		Integrated Broadband Noise	typ. 20 mV peak-peak or 3.5 mV rms	(@ $\geq 1 \text{ M}\Omega$ load)	Power Supply	Supply Voltage	$\pm 15 \text{ V}$			Supply Current	$\pm 35 \text{ mA}$ typ. (depends on operating conditions, recommended power supply capability min. $\pm 100 \text{ mA}$)		Case	Weight	200 g (0.44 lb.)			Material	AlMg4.5Mn, nickel-plated		Temperature Range	Storage Temperature	-40 $^\circ\text{C}$ to +100 $^\circ\text{C}$			Operating Temperature	+20 $^\circ\text{C}$ to +40 $^\circ\text{C}$	
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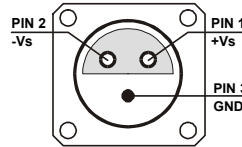
Preliminary Datasheet**HQA-15M-10T****High Frequency Charge Amplifier**

Absolute Maximum Ratings

Input Voltage	20 V peak-peak
Power Supply Voltage	± 18 V

Connectors

Input	BNC
Output	BNC
Power Supply	LEMO series 1S, 3-pin fixed socket Pin 1: + 15V Pin 2: - 15V Pin 3: GND



Operation

General:

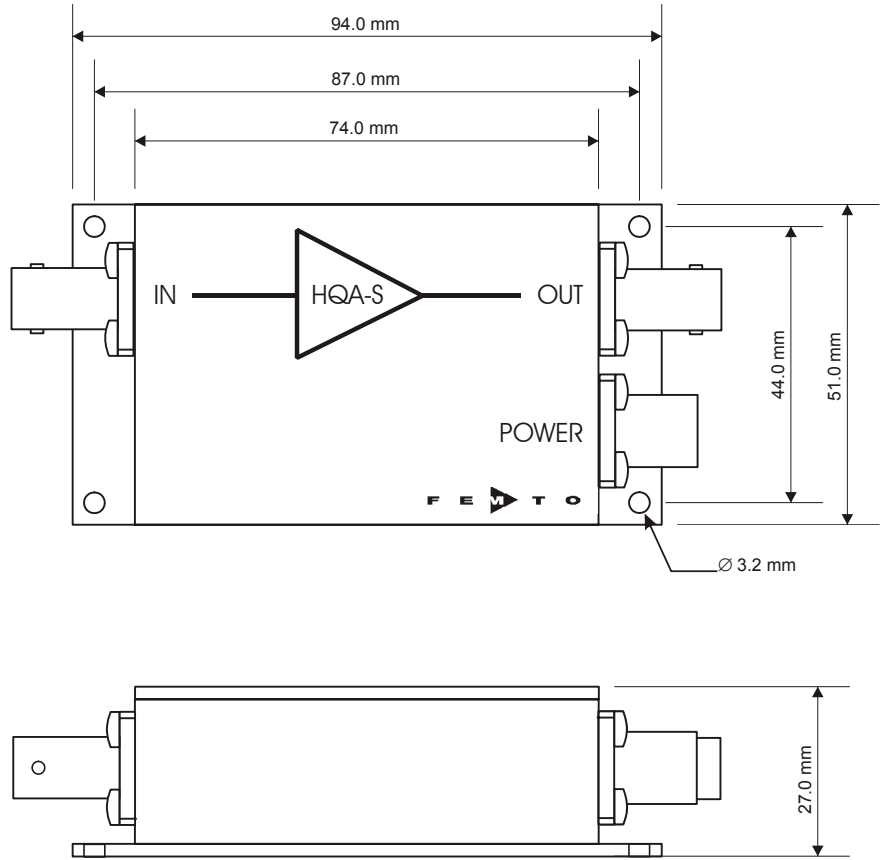
The amplifier is AC coupled for direct use with a charge sensor producing sinusoidal signals with no DC background. A source capacitance of less than 1 nF is recommended for proper operation. If the effective source capacitance (sensor plus cable capacitance) is small relative to the effective input impedance of the amplifier (10 nF) the amplifier acts as a virtual ground and most of the charge flows into the amplifier input. At 1 MHz the amplifier input capacitance of 10 nF corresponds to a complex input impedance of 20Ω . An input resistor of $1 \text{ G}\Omega$ is incorporated to prevent buildup of static charge. The amplifier is not suited for sources producing an average DC background current as this would saturate the device.

Preliminary Datasheet

HQA-15M-10T

High Frequency Charge Amplifier

Dimensions



DZ01-2299001-R1

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SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

